



# Solid State Devices, Inc.

14701 Firestone Blvd \* La Mirada, Ca 90638  
Phone: (562) 404-4474 \* Fax: (562) 404-1773  
ssdi@ssdi-power.com \* www.ssdi-power.com

## SHF1104 & SHF1104SMS thru SHF1109 & SHF1109SMS

### 1 AMP 400 - 900 V Hyper Fast Rectifier

**DESIGNER'S DATA SHEET**

**Part Number/Ordering Information <sup>1/</sup>**  
SHF11

**Screening <sup>2/</sup>**  
 — = Not Screened  
 TX = TX Level  
 TXV = TXV  
 S = S Level

**Package Type**  
 — = Axial Leaded  
 SMS = Surface Mount Square Tab

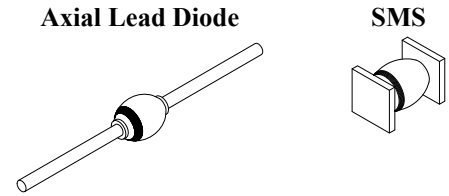
**Family/Voltage**  
 04 = 400 V  
 06 = 600 V  
 08 = 800 V  
 09 = 900 V

- Features:**
- Hyper Fast Recovery: 40 nsec maximum
  - PIV to 900 Volts, Consult Factory
  - Hermetically Sealed
  - Void Free Construction
  - For High Efficiency Applications
  - Replaces UES 1104, UES1106, IN6624
  - TX, TXV, S Level screening Available<sup>2/</sup>

Maximum Ratings		Symbol	Value	Units
<b>Peak Repetitive Reverse and DC Blocking Voltage</b>	SHF1104	$V_{RRM}$ $V_{RSM}$ $V_R$	400	Volts
	SHF1106		600	
	SHF1108		800	
	SHF1109		900	
<b>Average Rectified Forward Current</b> (Resistive Load, 60 hz Sine Wave, $T_A = 25\text{ }^\circ\text{C}$ )		$I_o$	1.0	Amps
<b>Peak Surge Current</b> (8.3 ms Pulse, Half Sine Wave, $T_A = 25\text{ }^\circ\text{C}$ )		$I_{FSM}$	20	Amps
<b>Operating &amp; Storage Temperature</b>		$T_{OP}$ & $T_{STG}$	-65 to +175	$^\circ\text{C}$
<b>Maximum Thermal Resistance</b>	Junction to Leads, L = 3/8 Junction to Tabs	$R_{\theta JE}$	35	$^\circ\text{C/W}$
			28	

**NOTES:**

- <sup>1/</sup> For Ordering Information, Price, and Availability- Contact Factory.  
<sup>2/</sup> Screening Based on MIL-PRF-19500. Screening Flows Available on Request.





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**SHF1104 & SHF1104SMS  
 thru  
 SHF1109 & SHF1109SMS**

Electrical Characteristic	Symbol	Max	Units
<b>Instantaneous Forward Voltage Drop</b> ( $I_F = 1A_{DC}$ , $T_A = 25^\circ C$ pulsed)	$V_F$	1.35	$V_{DC}$
<b>Instantaneous Forward Voltage Drop</b> ( $I_F = 1A_{DC}$ , $T_A = -55^\circ C$ pulsed)	$V_F$	1.5	$V_{DC}$
<b>Reverse Leakage Current</b> (Rated $V_R$ , $T_A = 25^\circ C$ pulsed)	$I_R$	10	$\mu A$
<b>Reverse Leakage Current</b> (Rated $V_R$ , $T_A = 100^\circ C$ pulsed)	$I_R$	1	mA
<b>Reverse Recovery Time</b> ( $I_F = 500mA$ , $I_R = 1A$ , $I_{RR} = 250mA$ , $T_A = 25^\circ C$ )	$t_{RR}$	40	nsec
<b>Junction Capacitance</b> ( $V_R = 10V_{DC}$ , $T_A = 25^\circ C$ , $f = 1MHz$ )	$C_J$	22	pF

**Case Outline: (Axial)**

DIM	MIN	MAX
A	0.100"	0.130"
B	0.130"	0.180"
C	0.027"	0.033"
D	1.00"	--

**Case Outline: (SMS)**

DIM	MIN	MAX
A	0.127"	0.140"
B	0.180"	0.230"
C	0.020"	0.030"
D	0.002"	--